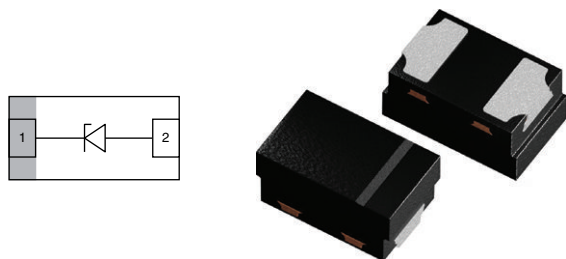




## Single-Line Unidirectional ESD-Protection Diode in DFN1006-2A



## MARKING (example only)



Bar = pin 1 marking

X = date code

YY = type code (see table below)

## LINKS TO ADDITIONAL RESOURCES



## FEATURES

- Compact DFN1006-2A package
- Low package height < 0.5 mm
- 1-line unidirectional ESD-protection
- AEC-Q101 qualified available
- Working range 14 V; 28 V
- ESD immunity acc. IEC 61000-4-2
  - ±15 kV to ±30 kV contact discharge
  - ±15 kV to ±30 kV air discharge
- Lead plating: Sn (e3)
  - Soldering can be checked by standard vision inspection
  - AOI = Automated Optical Inspection
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



## Soldering Recommendations for DFN Packages:

please see Application Note: [www.vishay.com/doc?86198](http://www.vishay.com/doc?86198)

## ORDERING INFORMATION

| PART NUMBER<br>(EXAMPLE) | AEC-Q101<br>QUALIFIED | ENVIRONMENTAL AND QUALITY CODE                     |               |                                | ORDERING CODE (EXAMPLE) |
|--------------------------|-----------------------|--|---------------|--------------------------------|-------------------------|
|                          |                       | RoHS COMPLIANT +<br>LEAD (Pb)-FREE<br>TERMINATIONS | TIN<br>PLATED | 10K PER 7" REEL<br>(8 mm TAPE) |                         |
|                          |                       | GREEN  |               | MOQ = 10K/BOX                  |                         |
| VMMBZ16C1HD1             | -                     | G  | 3             | -08                            | VMMBZ16C1HD1-G3-08      |
| VMMBZ16C1HD1             | H                     | G  | 3             | -08                            | VMMBZ16C1HD1HG3-08      |

## PACKAGE DATA

| DEVICE NAME  | PACKAGE NAME | TYPE CODE | WEIGHT  | MOLDING COMPOUND<br>FLAMMABILITY RATING | MOISTURE<br>SENSITIVITY LEVEL        | SOLDERING<br>CONDITIONS         |
|--------------|--------------|-----------|---------|---|--------------------------------------|---------------------------------|
| VMMBZ16C1HD1 | DFN1006-2A   | 2X        | 0.83 mg | UL 94 V-0                               | MSL level 1<br>(according J-STD-020) | Peak temperature<br>max. 260 °C |
| VMMBZ33C1HD1 | DFN1006-2A   | 2L        | 0.83 mg | UL 94 V-0                               | MSL level 1<br>(according J-STD-020) | Peak temperature<br>max. 260 °C |

**ABSOLUTE MAXIMUM RATINGS** VMMBZ16C1HD1(T<sub>amb</sub> = 25 °C, unless otherwise specified)

| PARAMETER             | TEST CONDITIONS  | SYMBOL           | VALUE       | UNIT |
|-----------------------|--|------------------|-------------|------|
| Peak pulse current    | Acc. IEC 61000-4-5, 8/20 µs/single shot                        | I <sub>PPM</sub> | 4           | A    |
| Peak pulse power      | Acc. IEC 61000-4-5, 8/20 µs/single shot <sup>(1)</sup>         | P <sub>PP</sub>  | 108         | W    |
| Peak pulse current    | t <sub>p</sub> = 10/1000 µs <sup>(1)</sup>                     | I <sub>PPM</sub> | 0.7         | A    |
| Peak pulse power      | t <sub>p</sub> = 10/1000 µs <sup>(1)</sup>                     | P <sub>PP</sub>  | 16          | W    |
| ESD immunity          | Contact discharge acc. IEC 61000-4-2; 10 pulses <sup>(1)</sup> | V <sub>ESD</sub> | 30          | kV   |
|                       | Air discharge acc. IEC 61000-4-2; 10 pulses <sup>(1)</sup>     |                  | 30          | kV   |
| Operating temperature | Junction temperature   | T <sub>J</sub>   | -55 to +150 | °C   |
| Storage temperature   |  | T <sub>stg</sub> | -55 to +150 | °C   |

**Note**<sup>(1)</sup> Guaranteed by design; tested during device characterization**ABSOLUTE MAXIMUM RATINGS** VMMBZ33C1HD1(T<sub>amb</sub> = 25 °C, unless otherwise specified)

| PARAMETER             | TEST CONDITIONS  | SYMBOL           | VALUE       | UNIT |
|-----------------------|--|------------------|-------------|------|
| Peak pulse current    | Acc. IEC 61000-4-5, 8/20 µs/single shot                        | I <sub>PPM</sub> | 1.7         | A    |
| Peak pulse power      | Acc. IEC 61000-4-5, 8/20 µs/single shot <sup>(1)</sup>         | P <sub>PP</sub>  | 100         | W    |
| Peak pulse current    | t <sub>p</sub> = 10/1000 µs <sup>(1)</sup>                     | I <sub>PPM</sub> | 0.3         | A    |
| Peak pulse power      | t <sub>p</sub> = 10/1000 µs <sup>(1)</sup>                     | P <sub>PP</sub>  | 15          | W    |
| ESD immunity          | Contact discharge acc. IEC 61000-4-2; 10 pulses <sup>(1)</sup> | V <sub>ESD</sub> | 15          | kV   |
|                       | Air discharge acc. IEC 61000-4-2; 10 pulses <sup>(1)</sup>     |                  | 15          | kV   |
| Operating temperature | Junction temperature   | T <sub>J</sub>   | -55 to +150 | °C   |
| Storage temperature   |  | T <sub>stg</sub> | -55 to +150 | °C   |

**Note**<sup>(1)</sup> Guaranteed by design; tested during device characterization**ELECTRICAL CHARACTERISTICS** VMMBZ16C1HD1(T<sub>amb</sub> = 25 °C, unless otherwise specified)

| PARAMETER                 | TEST CONDITIONS / REMARKS   | SYMBOL               | MIN. | TYP.    | MAX. | UNIT  |
|---------------------------|---|----------------------|------|---------|------|-------|
| Protection paths          | Number of lines which can be protected                                      | N <sub>channel</sub> | -    | -       | 1    | lines |
| Reverse stand off voltage | Max. reverse working voltage  | V <sub>RWM</sub>     | -    | -       | 14   | V     |
| Reverse voltage           | At I <sub>R</sub> = 0.01 µA   | V <sub>R</sub>       | 14   | -       | -    | V     |
| Reverse current           | At V <sub>R</sub> = 14 V  | I <sub>R</sub>       | -    | < 0.001 | 0.01 | µA    |
|                           | At V <sub>R</sub> = 14 V; T <sub>J</sub> = 150 °C <sup>(1)</sup>            |                      | -    | 0.06    | 10   | µA    |
| Reverse breakdown voltage | At I <sub>R</sub> = 1 mA  | V <sub>BR</sub>      | 15.2 | 16      | 16.8 | V     |
|                           | At I <sub>R</sub> = 1 mA; T <sub>J</sub> = -40 °C to +150 °C <sup>(1)</sup> |                      | 14.3 | -       | 19.0 | V     |
| Reverse clamping voltage  | At I <sub>PP</sub> = I <sub>PPM</sub> = 4 A, t <sub>p</sub> = 8/20 µs       | V <sub>C</sub>       | 19   | 23      | 27   | V     |
|                           | t <sub>p</sub> = 100 ns (TLP); I <sub>TLP</sub> = 16 A <sup>(1)</sup>       | V <sub>C_TLP</sub>   | -    | 24      | -    | V     |
| Dynamic resistance        | t <sub>p</sub> = 100 ns (TLP) <sup>(1)</sup>                                | r <sub>dyn</sub>     | -    | 0.48    | -    | Ω     |
| Capacitance               | At V <sub>R</sub> = 0 V; f = 1 MHz  | C <sub>D</sub>       | 24.6 | 29      | 33.4 | pF    |

**Note**<sup>(1)</sup> Guaranteed by design; tested during device characterization

**ELECTRICAL CHARACTERISTICS VMMBZ33C1HD1**(T<sub>amb</sub> = 25 °C, unless otherwise specified)

| PARAMETER                 | TEST CONDITIONS / REMARKS   | SYMBOL               | MIN. | TYP.    | MAX. | UNIT  |
|---------------------------|---|----------------------|------|---------|------|-------|
| Protection paths          | Number of lines which can be protected                                      | N <sub>channel</sub> | -    | -       | 1    | lines |
| Reverse stand off voltage | Max. reverse working voltage  | V <sub>RWM</sub>     | -    | -       | 28   | V     |
| Reverse voltage           | At I <sub>R</sub> = 0.01 µA   | V <sub>R</sub>       | 28   | -       | -    | V     |
| Reverse current           | At V <sub>R</sub> = 28 V  | I <sub>R</sub>       | -    | < 0.001 | 0.01 | µA    |
|                           | At V <sub>R</sub> = 28 V; T <sub>J</sub> = 150 °C <sup>(1)</sup>            |                      | -    | 0.1     | 10   | µA    |
| Reverse breakdown voltage | At I <sub>R</sub> = 1 mA  | V <sub>BR</sub>      | 31.3 | 33      | 34.7 | V     |
|                           | At I <sub>R</sub> = 1 mA; T <sub>J</sub> = -40 °C to +150 °C <sup>(1)</sup> |                      | 29   | -       | 39   | V     |
| Reverse clamping voltage  | At I <sub>PP</sub> = I <sub>PPM</sub> = 1.7 A, t <sub>p</sub> = 8/20 µs     | V <sub>C</sub>       | 40   | 49      | 59   | V     |
|                           | t <sub>p</sub> = 100 ns (TLP); I <sub>TLP</sub> = 16 A <sup>(1)</sup>       | V <sub>C,TLP</sub>   | -    | 85      | -    | V     |
| Dynamic resistance        | t <sub>p</sub> = 100 ns (TLP) <sup>(1)</sup>                                | r <sub>dyn</sub>     | -    | 0.34    | -    | Ω     |
| Capacitance               | At V <sub>R</sub> = 0 V; f = 1 MHz  | C <sub>D</sub>       | 13.6 | 16.1    | 18.6 | pF    |

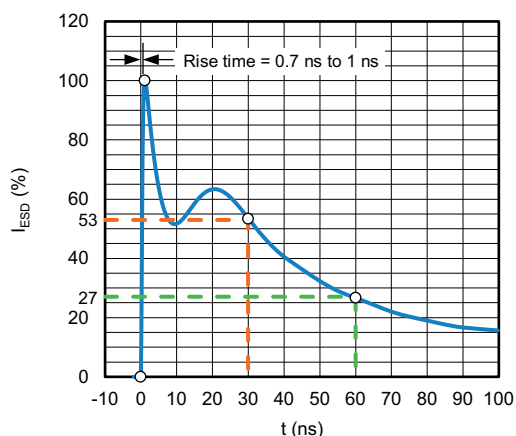
**Note**<sup>(1)</sup> Guaranteed by design; tested during device characterization**TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

Fig. 1 - ESD Discharge Current Wave Form According to IEC 61000-4-2 (330 Ω / 150 pF)

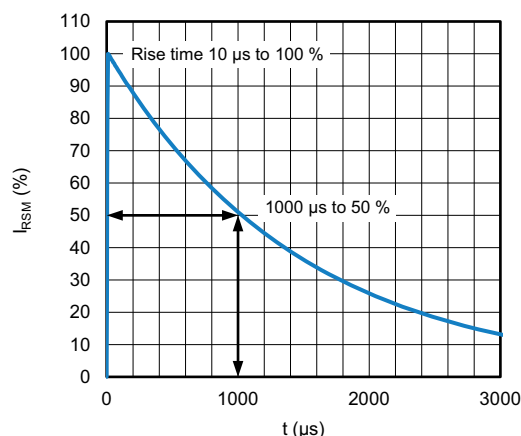


Fig. 3 - 10/1000 µs Peak Pulse Current Wave Form

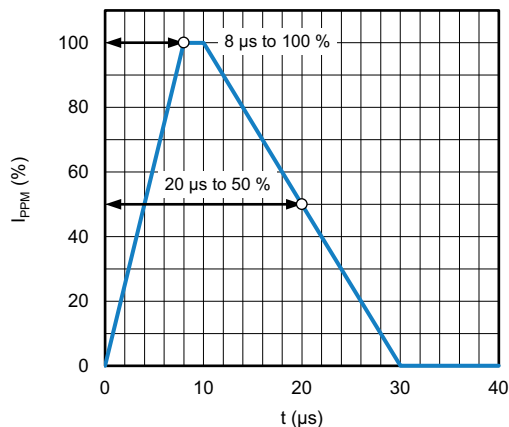


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form According to IEC 61000-4-5

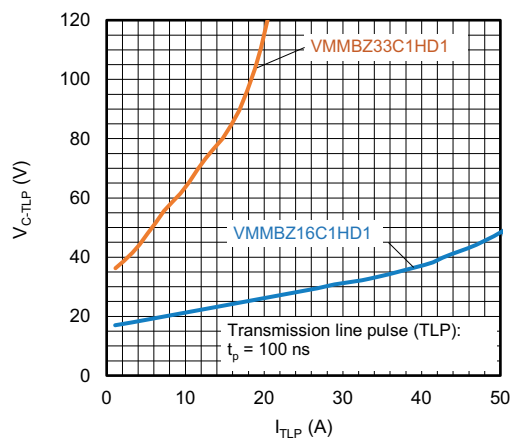


Fig. 4 - Typical Clamping Voltage vs. Peak Pulse Current

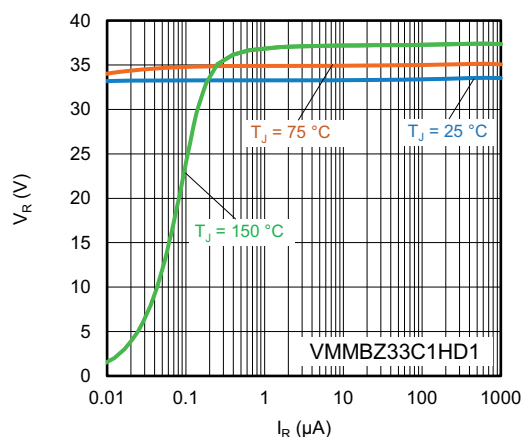


Fig. 5 - Typical Reverse Voltage vs. Reverse Current

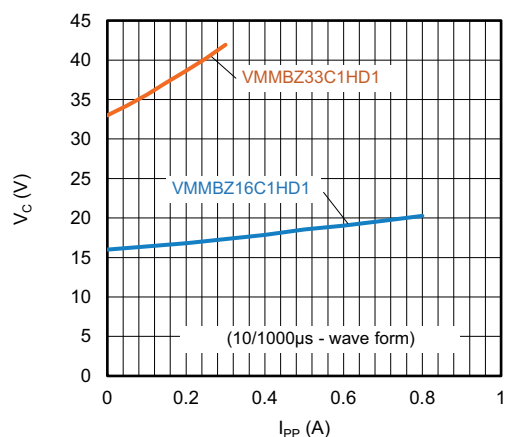


Fig. 8 - Typical Peak Clamping Voltage vs. Peak Pulse Current

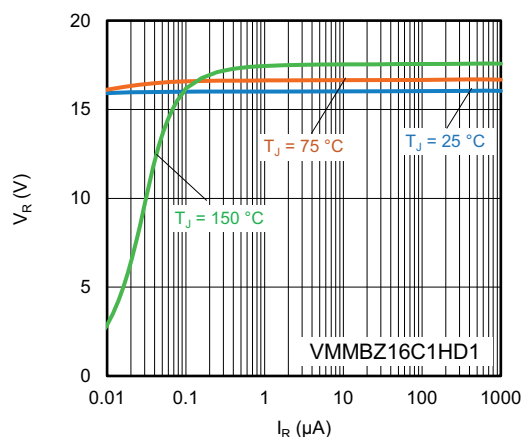


Fig. 6 - Typical Reverse Voltage vs. Reverse Current

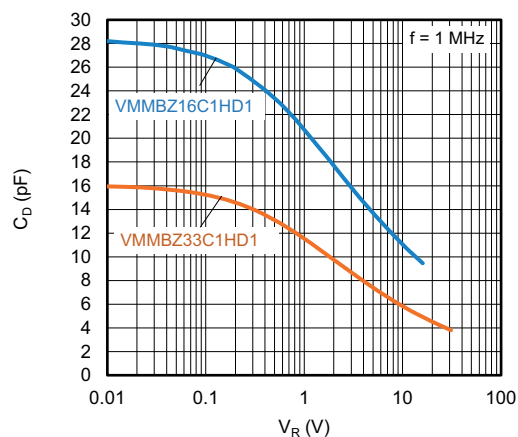


Fig. 9 - Typical Capacitance vs. Reverse Voltage

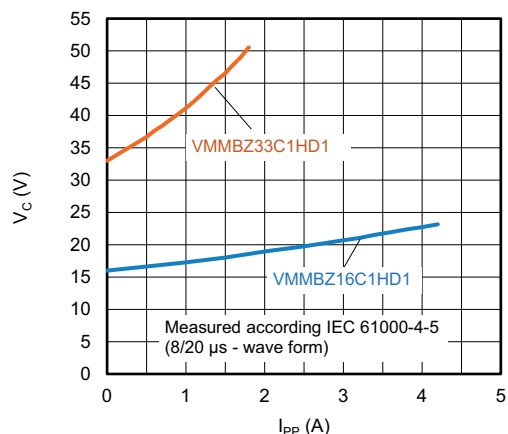
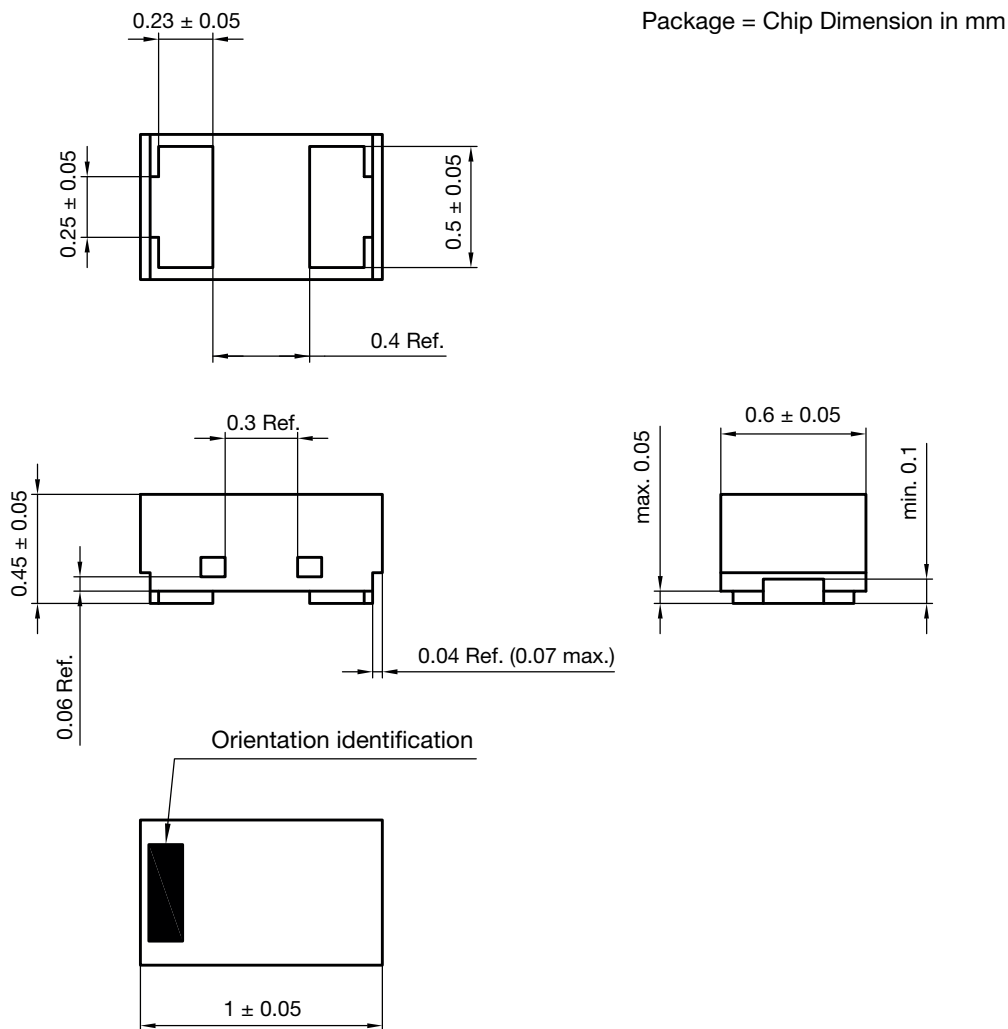


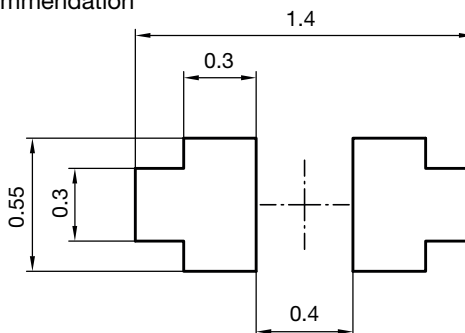
Fig. 7 - Typical Peak Clamping Voltage vs. Peak Pulse Current



## PACKAGE DIMENSIONS in millimeters (Inches): DFN1006-2A



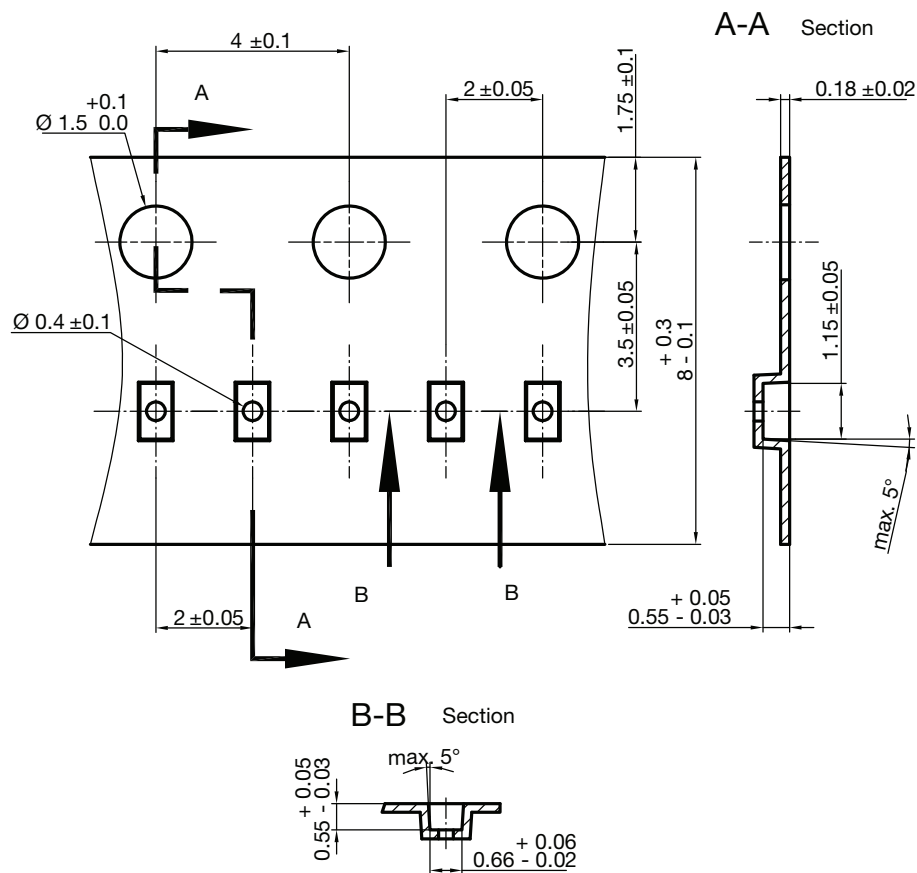
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Document no.: S8-V-3906.04-059 (4)  
Created - Date: 11-Jul-2018  
Rev.5 - Date: 17-Sep-2021

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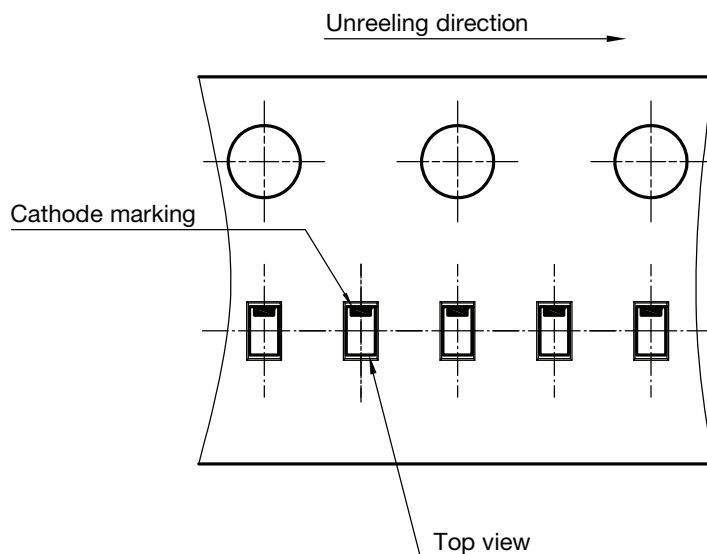
## CARRIER TAPE DFN1006-2A



S8-V-3906.04-063 (4)  
created 28.10.2019

surface resistance:  $10^5 - 10^{11} \frac{\text{OHMS}}{\text{SQ}}$   
Cumulative tolerances of 10 sprocket holes is  $\pm 0.2 \text{ mm}$

## ORIENTATION IN CARRIER TAPE DFN1006-2A



S8-V-3906.04-064 (4)  
created 28.10.2019



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